



High-end Power Semiconductor Manufacturer

MDS200**Three Phases Rectification Bridge Modules****Features:**

- Isolated mounting base 2500V
- Solder joint technology
- Space and weight savings

I_O	200 A
V_{RRM}	600~2200 V
I_{FSM}	1.50 KA
I²t	11.25$10^3$A²s

Typical Applications

- DC Power supplies for equipments.
- DC supply for PWM inverter
- Inverter Welder

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T _j (°C)	VALUE			UNIT
				Min	Type	Max	
I _O	DC output current	Three-phase full wave rectifying circuit, T _C =100°C	150			200	A
I _{RRM}	Repetitive peak current	at V _{RRM}	150			12	mA
I _{FSM}	Surge forward current	10ms half sine wave	150			1.5	kA
I ² t	I ² t for fusing coordination	V _R =0				11.25	10 ³ A ² s
V _{FO}	Threshold voltage		150			0.75	V
r _F	Forward slope resistance					2.0	mW
V _{FM}	Peak forward voltage	I _{FM} =200A	25			1.50	V
R _{th(j-c)}	Thermal resistance Junction to case	Single side cooled, per total				0.10	°C/W
R _{th(c-h)}	Thermal resistance case to heatsink	Single side cooled, per total				0.07	°C/W
V _{iso}	Isolation voltage	50Hz,R.M.S,t=1min,I _{iso} :1mA(max)		2500			V
F _m	Terminal connection torque(M6)			4.5		6.0	N·m
	Mounting torque(M6)			4.5		6.0	N·m
T _{vj}	Junction temperature			-40		150	°C
T _{stg}	Stored temperature			-40		125	°C
W _t	Weight				240		g
Outline			T15				

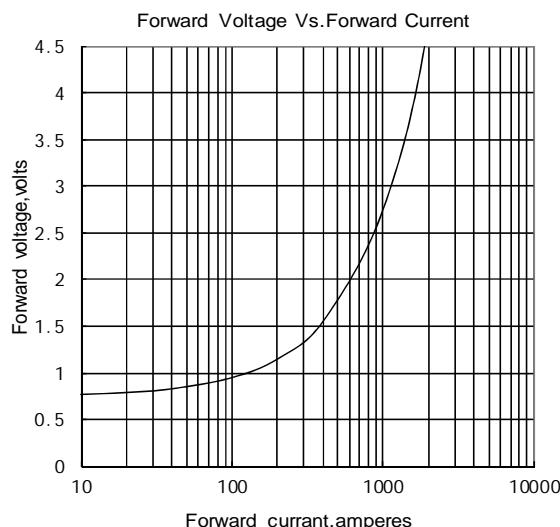


Fig.1

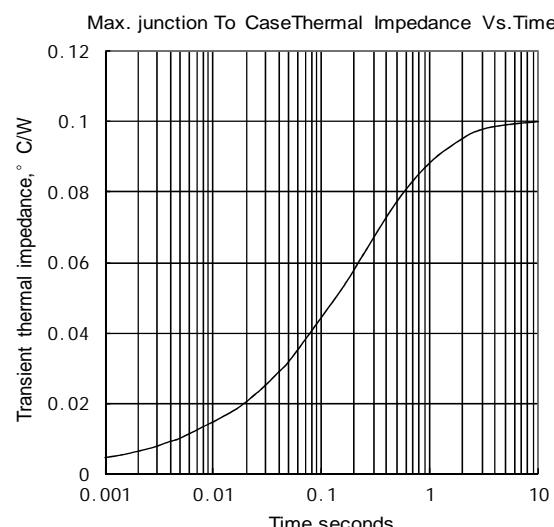


Fig.2

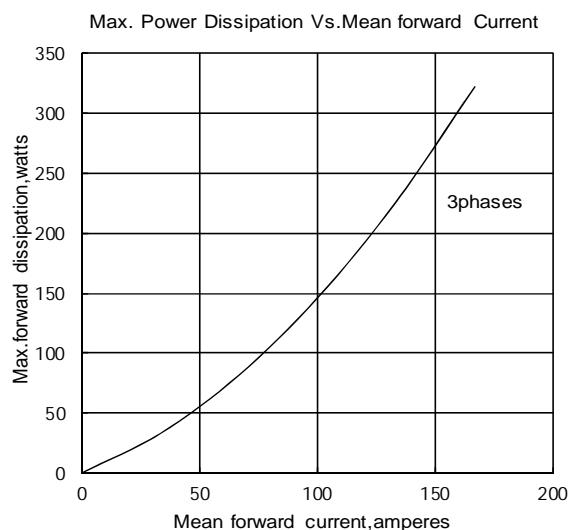


Fig.3

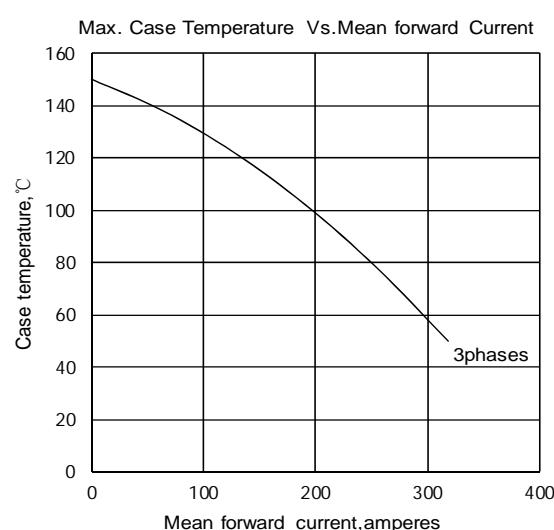


Fig.4

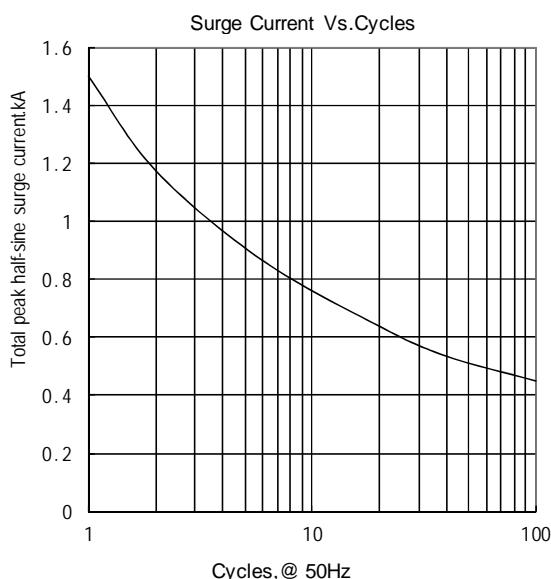


Fig.5

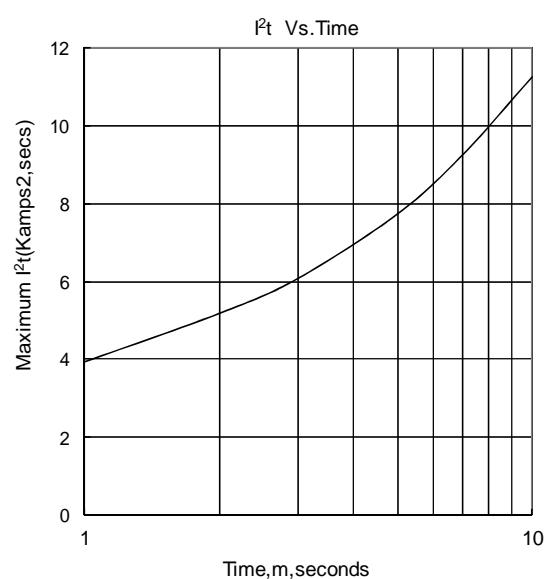
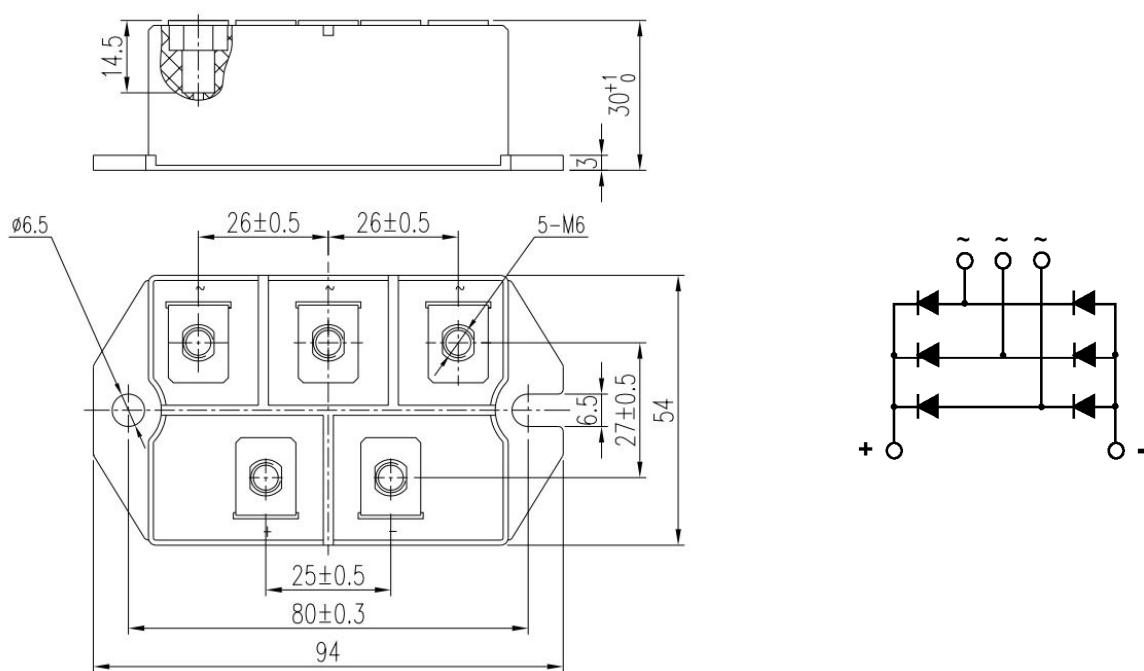


Fig.6

Outline:

Unmarked dimensional tolerance: ±0.5mm

T15